

PTVSLC23T12VU

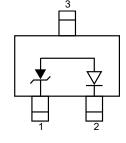
Low Capacitance TVS Array

Description

The PTVSLC23T12VU of TVS arrays are designed to protect sensitive electronics from damage or latch-up due to ESD, lightning, and other voltage-induced transient events. It is available with operating voltages of 12V.

TVS diodes are solid-state devices designed specifically for transient suppression. It offer desirable characteristics for board level protection including fast response time, low operating and clamping voltage, and no device degradation. The PTVSLC23T12VU devices feature a low capacitance, fast switching compensation diode in series with a standard TVS diode. This effectively reduces the overall capacitance of the device to less than 5pF making it an integrated, low capacitance solution for use on high-speed interfaces.

The PTVSLC23T12VU devices may be used to meet the immunity requirements of IEC 61000-4-2, level 4.



Feature

- 600W peak pulse power (t_P = 8/20µs)
- SOT-23 package
- Working voltage: 12V
- Low clamping voltage
- Low capacitance
- RoHS compliant transient protection for high speed data lines to IEC61000-4-2(ESD)±30kV(air),±30kV(Contact)

Mechanical Characteristics

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C
- Device meets MSL 1 requirements
- Pure tin plating: 7 ~ 17 um
- ➢ Pin flatness:≤3mil

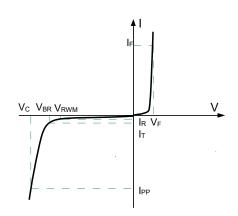
Applications

- Cellular handsets and accessories
- Portable electronics
- LAN/WAN equipment
- High speed data lines
- Fire wire

PTVSLC23T12VU

Electronics Parameter

Symbol	Parameter		
V _{RWM}	Peak Reverse Working Voltage		
I _R	Reverse Leakage Current @ VRWM		
V _{BR}	Breakdown Voltage @ I⊤		
Iτ	Test Current		
IPP	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ IPP		
P _{PP}	Peak Pulse Power		
CJ	Junction Capacitance		
IF	Forward Current		
VF	Forward Voltage @ I⊧		



Absolute maximum rating@25℃

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Reverse Stand-off Voltage	VRWM				12	V
Reverse Breakdown Voltage	V _{BR}	It = 1mA	15.0		18.5	V
Reverse Leakage Current	IR	V _{RWM} =12V, T=25℃			1	μA
Clamping Voltage	Vc	I _{PP} = 1A, t _P = 8/20µs			18.8	V
Clamping Voltage	Vc	I _{PP} =5A, t _P = 8/20µs			22.0	V
Junction Capacitance	CJ	V _R =0V, f = 1MHz		3		pF

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Peak Pulse Power (t _p =8/20µs)	P _{pp}	600	W
Operating Temperature	TJ	-55 to +125	°C
Storage Temperature	Тѕтс	-55 to +125	°C

PTVSLC23T12VU

Typical Characteristics

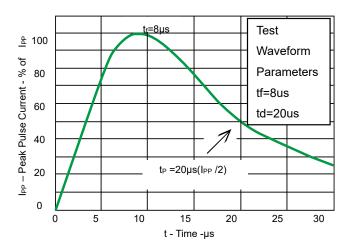


Fig 1.Pulse Waveform

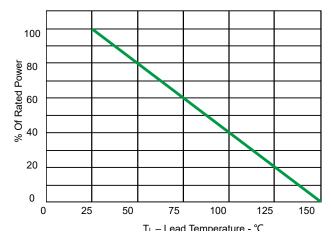


Fig 2.Power Derating Curve

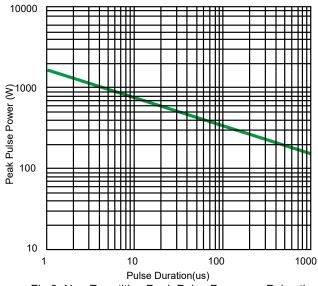
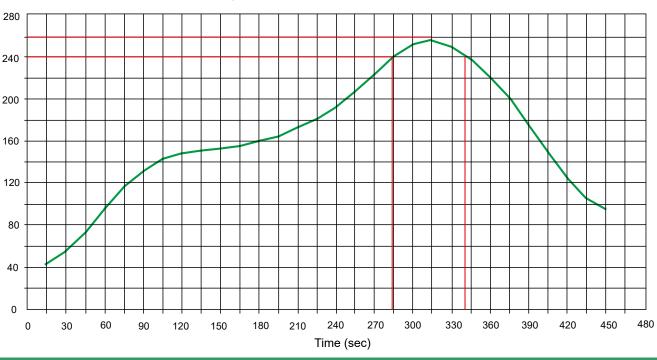


Fig 3. Non Repetitive Peak Pulse Power vs. Pulse time

PTVSLC23T12VU

Solder Reflow Recommendation



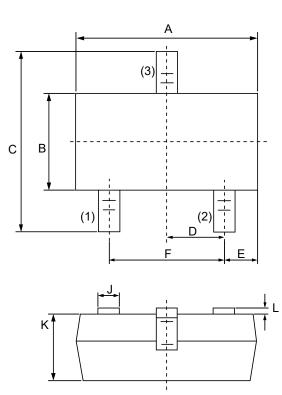
Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec

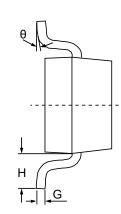
PCB Design

For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- > Keep the length of via holes in mind! The longer the more inductance they will have.

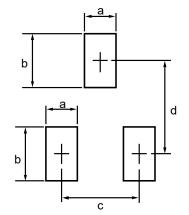
Product dimension(SOT-23)





Dim	Millimeters		Inches		
Dim	MIN	МАХ	MIN	MAX	
А	2.80	3.00	0.1102	0.1197	
В	1.20	1.40	0.0472	0.0551	
С	2.10	2.50	0.0830	0.0984	
D	0.89	1.02	0.0350	0.0401	
E	0.45	0.60	0.0177	0.0236	
F	1.78	2.04	0.0701	0.0807	
G	0.085	0.177	0.0034	0.0070	
н	0.45	0.60	0.0180	0.0236	
J	0.37	0.50	0.0150	0.0200	
К	0.89	1.11	0.0350	0.0440	
L	0.013	0.100	0.0005	0.0040	
θ	0°	10°	0°	10°	

PTVSLC23T12VU

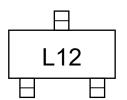


Dim	Millimeters			
Dim	MIN	МАХ		
а		0.7		
b	-	1.2		
с		2.04		
d		2.2		

Ordering information

Device	Package	Shipping
PTVSLC23T12VU	SOT-23 (Pb-Free)	3000 / Tape & Reel

Marking information



IMPORTANT NOTICE

(P) and **Prisemi** are registered trademarks of **Prisemi Electronics Co., Ltd** (Prisemi), Prisemi reserves the right to make changes without further notice to any products herein. Prisemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Prisemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in Prisemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Prisemi does not convey any license under its patent rights nor the rights of others. The products listed in this document are designed to be used with ordinary electronic equipment or devices, Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

Website: http://www.prisemi.com For additional information, please contact your local Sales Representative. ©Copyright 2009, Prisemi Electronics Prisemi[®] is a registered trademark of Prisemi Electronics. All rights are reserved.